

# AM4959S H-Bridge Brushed DC Motor Driver

## ● Features

- Operating Voltage Range : 5 to 30V
- Low Rds(on): HS + LS = 170mΩ
- 2.2A Continuous Current, 4A Peak Current
- Low standby current < 2μA
- Current Limit Protection
- Overcurrent Protection
- Over Temperature Protection
- SOP8 Package for small PCB layout
- Halogen-Free Green Product & RoHS compliant Package

## ● Application

- Robotics
- AI Home Appliances
- Robot Vacuum
- Printer
- Electric Curtains
- Industrial Equipment
- Other Mechatronic Applications

## ● Description

AM4959S is a brushed DC motor driver IC, provides outside PWM pulse to control motor speed, and it drives current capability up to 2.2A continuous and 4A peak.

The device provides well protection for motor and device itself including internal functions for overcurrent, current limit, and over temperature protection.

## ● Ordering Information

| Orderable Part Number | Package | Marking |
|-----------------------|---------|---------|
| AM4959S               | SOP-8   | AM4959S |

● **Absolute Maximum Ratings ( $T_A=25^{\circ}\text{C}$ )**

| Parameter                          | Symbol      | Limit       | Unit               |
|------------------------------------|-------------|-------------|--------------------|
| Power Supply Voltage               | VCC         | 40          | V                  |
| VREF Input Voltage                 | VREF        | -0.3 to 6   | V                  |
| Signal Input IN_A and IN_B Voltage | $V_{IN\_X}$ | -0.3 to 6   | V                  |
| Sense Voltage (LSS pin)            | $V_S$       | -0.5 to 0.6 | V                  |
| Output Voltage                     | $V_{OUT}$   | -0.3 to 40  | V                  |
| Peak Current                       | $I_{OUT}$   | 4           | A                  |
| Operate Temperature Range          | $T_{OPR}$   | -40~+125    | $^{\circ}\text{C}$ |
| Storage Temperature Range          | $T_{STG}$   | -40~+150    | $^{\circ}\text{C}$ |

● **ESD Rating**

|                                   |                                       | Value | Unit |
|-----------------------------------|---------------------------------------|-------|------|
| $V_{ESD}$ Electrostatic discharge | Human-body model (HBM) <sup>(1)</sup> | ±8000 | V    |
|                                   | Machine model (MM) <sup>(1)</sup>     | ±400  | V    |

(1) The test method refers to JEDEC EIA/JESD22-A114-B.

● **Recommended Operating Conditions ( $T_A = 25^{\circ}\text{C}$ )**

(Set the power supply voltage taking allowable dissipation into considering)

| Parameter                          | Symbol      | Min. | Typ. | Max.               | Unit |
|------------------------------------|-------------|------|------|--------------------|------|
| Power Supply Operating Voltage     | VCC         | 5    |      | 30                 | V    |
| Signal Input IN_A and IN_B Voltage | $V_{IN\_X}$ | -0.3 |      | 6 <sup>(1)</sup>   | V    |
| VREF Input Voltage                 | VREF        | 0.3  |      | 5                  | V    |
| H-Bridge Output Current            | $I_{OUT}$   | 0    |      | 2.2 <sup>(2)</sup> | A    |
| Externally Applied PWM Frequency   | $f_{IN\_X}$ |      |      | 30                 | kHz  |

(1) Input signal voltage does not be higher than VCC voltage.

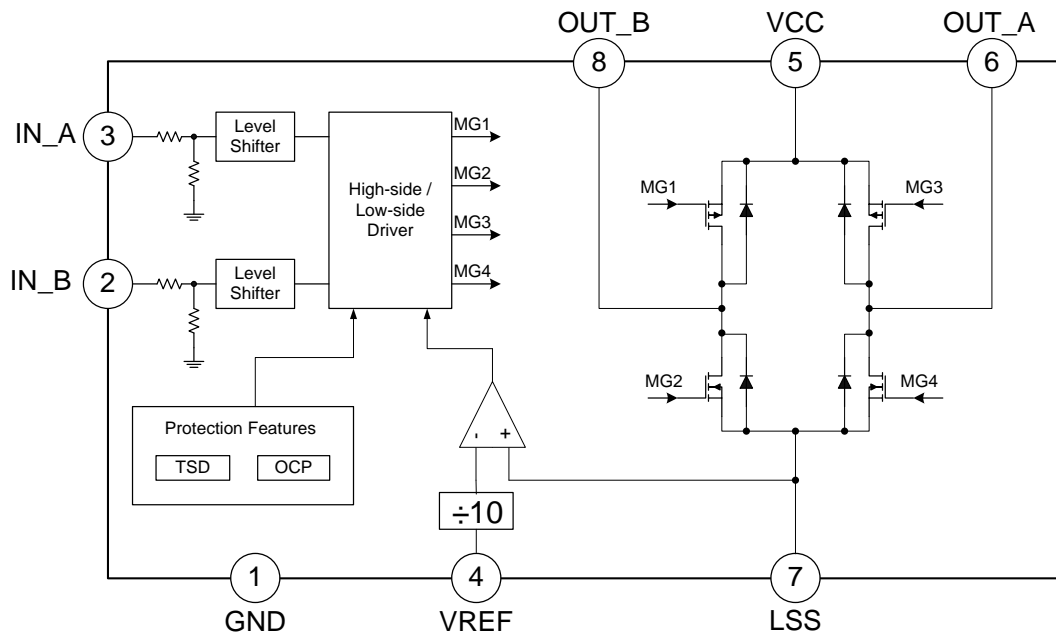
(2) Power dissipation and thermal limits must be observed

● **Electrical Characteristics ( Unless otherwise specified,  $T_A = 25^{\circ}\text{C}$ ,  $V_{CC}=12\text{V}$ )**

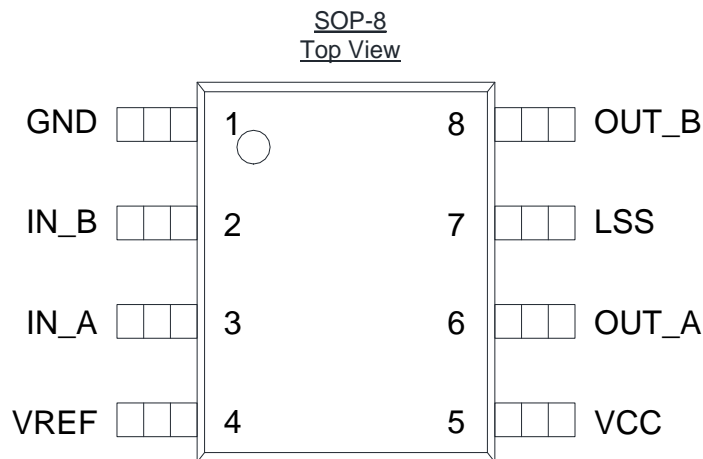
| Parameter                          | Symbol       | Limit |      |      | Unit               | Conditions                                       |
|------------------------------------|--------------|-------|------|------|--------------------|--|
|                                    |              | Min.  | Typ. | Max. |                    |  |
| <b>Power Supply</b>                |              |       |      |      |                    |  |
| Supply Current                     | $I_{CC}$     |       | 6    |      | mA                 | Input signal IN_A/B = L/H or H/L or H/H, no load |
| Standby Current                    | $I_{STB}$    |       |      | 2    | $\mu\text{A}$      | Input signal IN_A/B = L/L                        |
| <b>IN_X Inputs</b>                 |              |       |      |      |                    |  |
| Input H level Voltage              | $V_{IN\_XH}$ | 2.0   |      | 6    | V                  |  |
| Input L level Voltage              | $V_{IN\_XL}$ | -0.3  |      | 0.7  | V                  |  |
| Input H level Current              | $I_{IN\_X}$  |       | 100  |      | $\mu\text{A}$      | $V_{IN} = 3\text{V}$                             |
| Input Frequency                    | $f_{IN\_X}$  |       |      | 30   | kHz                |  |
| Input Pulldown Resistance          | $R_{IN\_X}$  |       | 30   |      | k $\Omega$         |  |
| <b>H-Bridge FETs</b>               |              |       |      |      |                    |  |
| On-Resistance                      | $R_{DS(ON)}$ |       | 170  |      | m $\Omega$         | $I_{OUT} = 1\text{A}$<br>Upper and Lower total   |
| On-Resistance                      | $R_{DS(ON)}$ |       | 225  |      | m $\Omega$         | $I_{OUT} = 2\text{A}$<br>Upper and Lower total   |
| <b>Current Limit Protection</b>    |              |       |      |      |                    |  |
| Current Gain                       | $A_V$        | 8     | 10   | 12   | V/V                | $V_{REF} = 2.5\text{V}$                          |
| PWM Blank Time                     | $T_{BLANK}$  |       | 3    |      | $\mu\text{s}$      |  |
| PWM Off-time                       | $T_{OFF}$    |       | 25   |      | $\mu\text{s}$      | $R + L = 80\text{ohm} + 5.5\text{mH}$            |
| <b>Overcurrent Protection</b>      |              |       |      |      |                    |  |
| Overcurrent Trip Level             | $I_{OCP}$    |       | 4    |      | A                  |  |
| <b>Thermal Shutdown Protection</b> |              |       |      |      |                    |  |
| Thermal Shutdown Protection        | $TSD_P$      |       | 160  |      | $^{\circ}\text{C}$ | *1   |
| Thermal Shutdown Release           | $TSD_R$      |       | 110  |      | $^{\circ}\text{C}$ | *1   |

\*1: It is design target, not to be measured at production test.

● Block Diagram



● Pin configuration



● **Pin Descriptions**

| Pin No. | Pin Name | I/O | Description                              |
|---------|----------|-----|--|
| 1       | GND      | I   | Ground Pin                               |
| 2       | IN_B     | I   | Logic Input B                            |
| 3       | IN_A     | I   | Logic Input A                            |
| 4       | VREF     | I   | Analog Input                             |
| 5       | VCC      | I   | Power Supply                             |
| 6       | OUT_A    | O   | Output Terminal A                        |
| 7       | LSS      | -   | Power Return – Sense Resistor Connection |
| 8       | OUT_B    | O   | Output Terminal B                        |

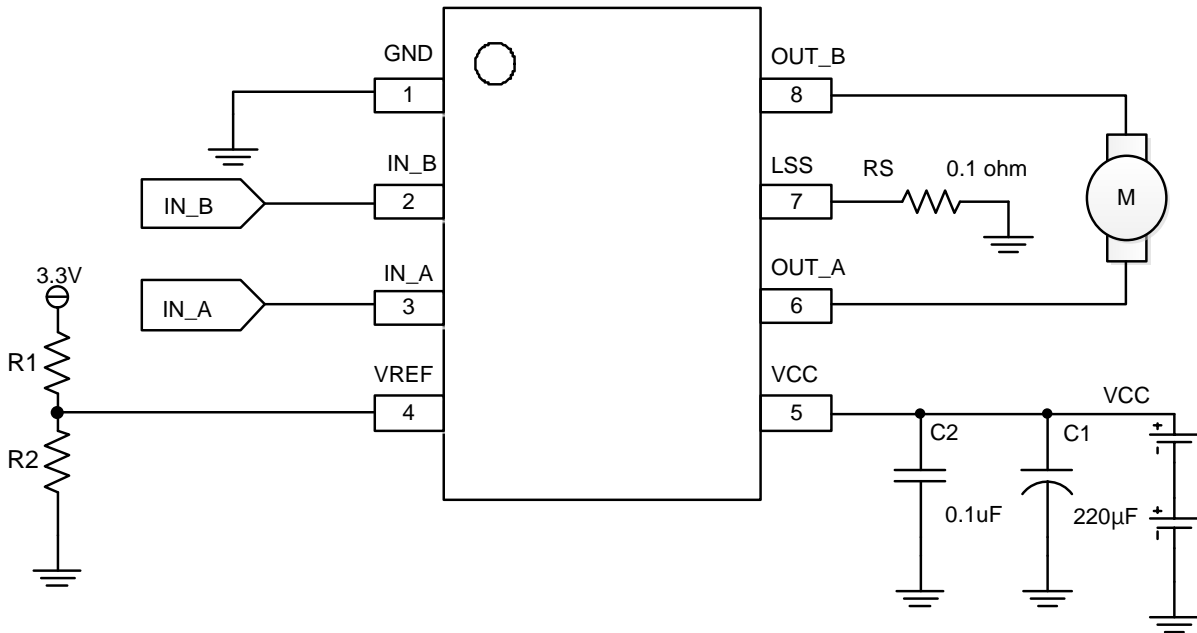
● **Input Logic Descriptions**

Function Truth Table

| IN_A | IN_B | OUT_A   | OUT_B  | Mode    |
|------|------|---------|--------|---------|
| L    | L    | High-Z* | High-Z | Stop    |
| L    | H    | L       | H      | Reverse |
| H    | L    | H       | L      | Forward |
| H    | H    | L       | L      | Brake   |

Note\*: “High-Z” is the status that High-side MOSFETs and Low-side MOSFETs of H-Bridge are switched to “OFF”.

● **Application:**



● **Circuit Descriptions**

The function descriptions of capacitors on the application circuit:

1. C1 、 C2: Power supply VCC pin capacitors:

The capacitors can reduce the power spike when the motor is in motion, and prevent the IC from damaging by the VCC peak voltage. They can stabilize the power supply voltage and reduce its ripples.

The C1 capacitor can compensate power supply when motor starts running.

The capacitor value ( $\mu\text{F}$ ) determines the stability of the VCC during motor is in motion. If the larger voltage power or a heavier loading motor is used, then a larger capacitor would be needed.

On the PCB configuration, the C1 、 C2 must be placed as close as possible to the VCC pin.

2. It's not allowed INA, INB input remain floating status, because there is a minor leakage current between P-N junction when temperature rising, the leakage current will flow through internal pull- low resistor which causes INA or INB floating level abnormal pull high and output abnormal working.

3. Sense Pin (LSS):

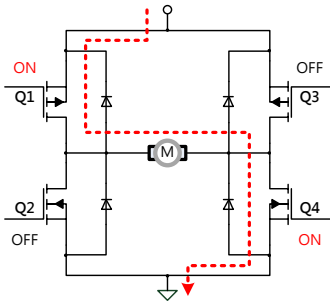
In order to use PWM current control, a low-value resistor is placed between the LSS pin and ground for current sensing purposes. The ground-trace should be as short as possible. For low-value sense resistors, the ground-trace voltage drops in the PCB could be significant, and should be taken into account.

When selecting a value for the sense resistor, be sure not to exceed the maximum voltage on the LSS pin of  $\pm 500$  mV at maximum load. During over-current events, this rating may be exceeded for short durations.

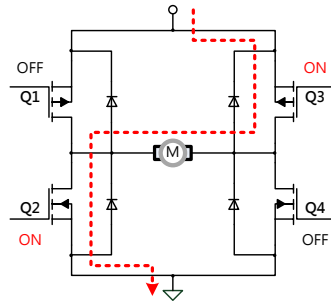
The resistance of the sense resistor must be rated for high enough power.

## ● Operating Mode Descriptions

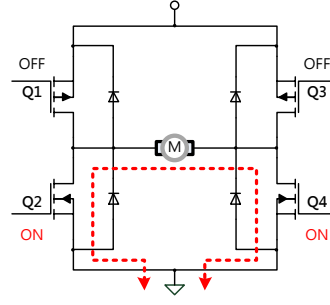
- a) Forward mode: When  $IN\_A=H$ ,  $IN\_B=L$ , then  $OUT\_A=H$ ,  $OUT\_B=L$
- b) Reverse mode: When  $IN\_A=L$ ,  $IN\_B=H$ , then  $OUT\_A=L$ ,  $OUT\_B=H$
- c) Brake mode: When  $IN\_A=IN\_B=H$ , then  $OUT\_A=OUT\_B=L$
- d) Stop mode: When  $IN\_A=IN\_B=L$ , then  $OUT\_A=OUT\_B=Hi-Z$



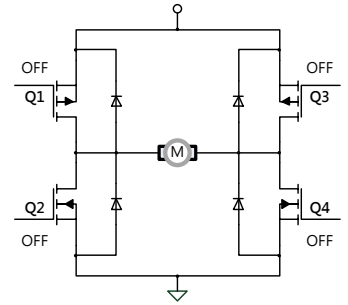
a) Forward mode



b) Reverse mode



c) Brake mode



d) Stop mode

● **Protection Mechanisms Descriptions**

(1) Overcurrent Protection:

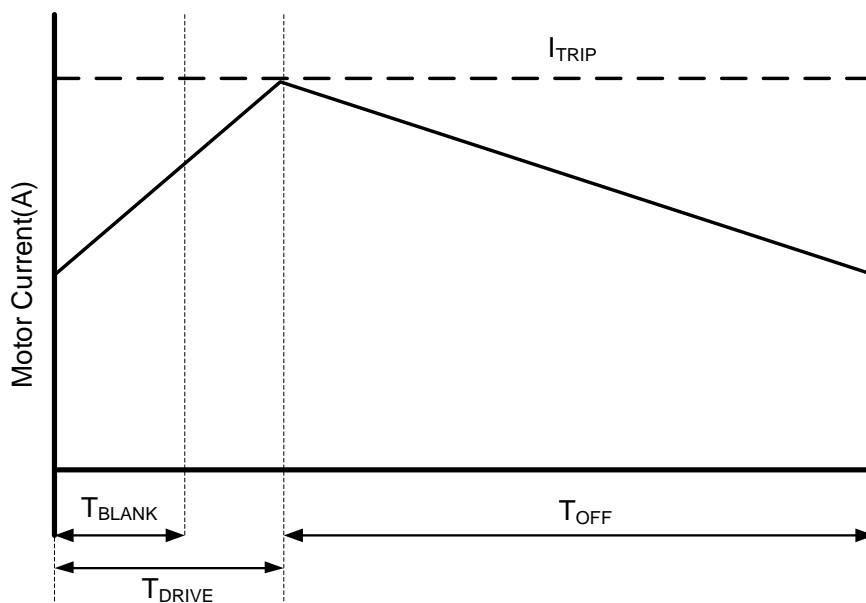
When the IC conducts a large current, 4A (Typ), the internal overcurrent protection will be triggered. The device enters protection mode and disables partial MOSFETs in the H-Bridge to avoid damaging IC and system. The device operation resumes when the current falls below safe range. If the overcurrent protection is still be triggered, the cycle repeats.

(2) Adjustable PWM Current Limit:

The AM4959S device limits the output current based on the analog input, VREF, and the resistance of an external sense resistor on the LSS pin according to the Equation:

$$I_{TRIP} = \frac{VREF(V)}{A_V \times R_S(\Omega)} = \frac{VREF(V)}{10 \times R_S(\Omega)}$$

For example, if VREF=2V and a  $R_S=0.1\Omega$ , the AM4959S device limits motor current to 2A no matter how much load torque is applied. When  $I_{TRIP}$  is reached, the device enforces slow current decay by enabling both low-side FETs, where the off time of R (8ohm) + L (5.5mH) is 25us.



Adjustable PWM Current Limit Time Periods

After  $T_{OFF}$  elapses, the output is re-enabled according to the two inputs, IN\_A and IN\_B. The drive time ( $T_{DRIVE}$ ) and  $T_{OFF}$  until reaching another  $I_{TRIP}$  event heavily depends on the motor voltage, the back-EMF of the motor, and the inductance of the motor.

(3) Thermal Shutdown (TSD):

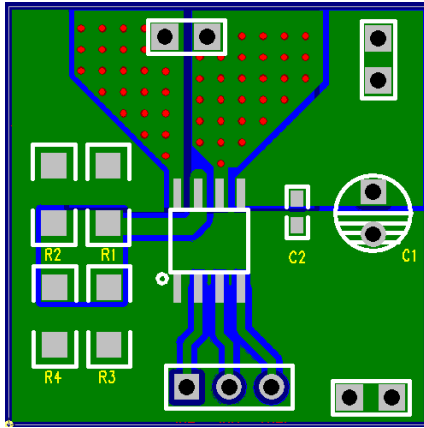
If the IC junction temperature exceeds 160°C (Typ.), the internal thermal shutdown protection will be triggered, and then partial FETs in the H-Bridge are disabled so that it will ensure the safety of customers' products. If the IC junction temperature falls to 110°C (Typ.), the IC resumes automatically.



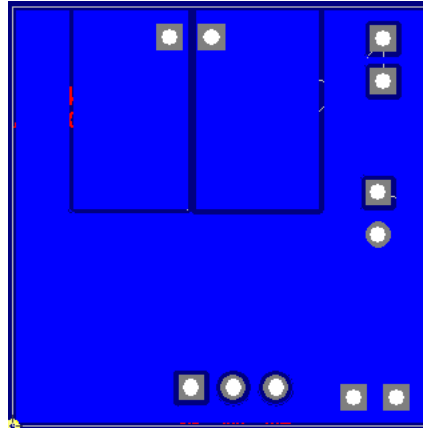
## ● Layout Guidelines

### 1. Layout Example:

PCB Size 25x25 mm<sup>2</sup> \ double-sided printed board.



Top Layer



Bottom Layer

### 2. Layout Consideration:

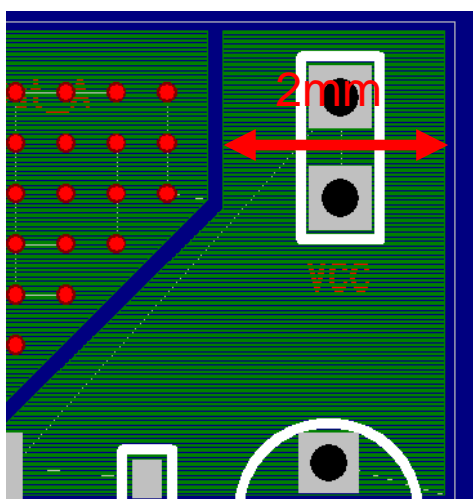
The layout is very important when designing high current and high frequency switching converters. Layout will affect noise pickup. Correct layout can realize a good design with less background noise. Make all the connections for the power components in the top layer with wide copper filled areas or polygons. In general, it is desirable to make proper use of GND planes and polygons for power distribution and heat dissipation.

### 3. Power Trace:

Power trace (VCC) should be as short as possible.

On the PCB configuration, the C1 and C2 must be placed as close as possible to the VCC pin in order to reduce EMI noise.

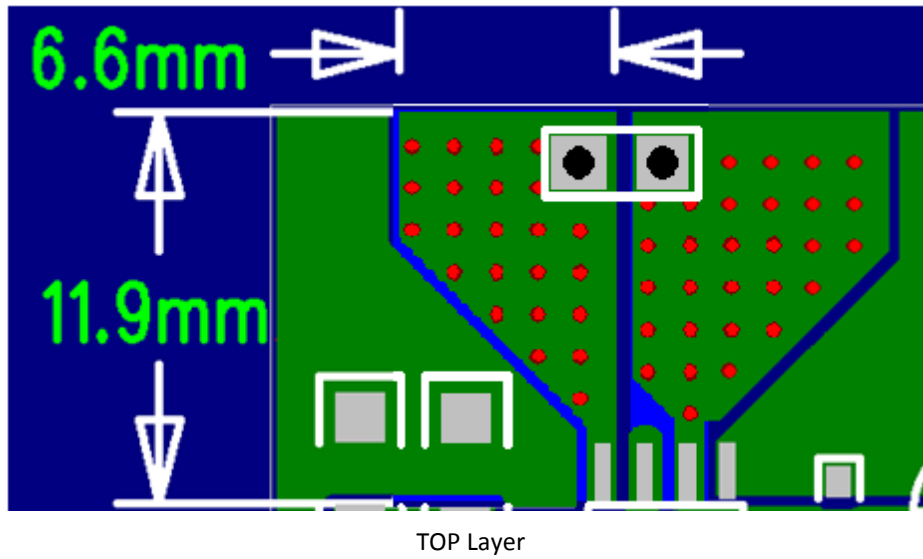
To ensure that power trace can conduct high current, the width of power trace should be wider than 2 mm.



### 4. Output Trace:

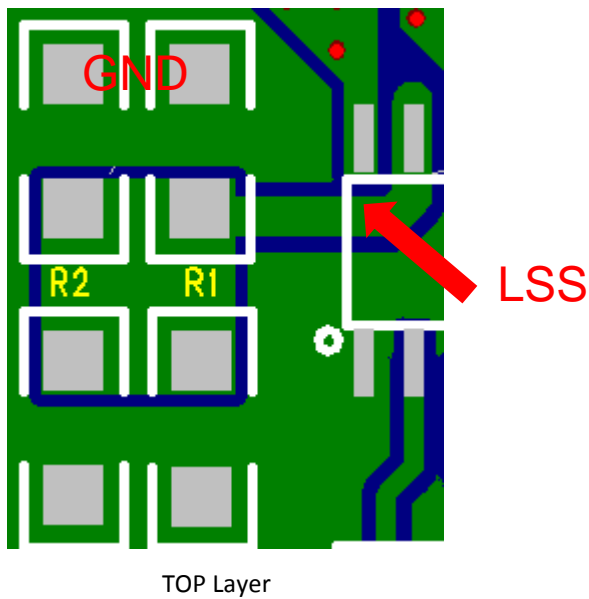
OUT\_A and OUT\_B trace width need at least 2mm for high current flowing through.

For OUT\_A & OUT\_B thermal design consideration, it should increase copper area widely (for example: 11.9mm x 6.6mm) without any gaps.



5. LSS (Sense Pin):

LSS is high-current path through the motor driver. The width of connecting metal trace should be as wide as possible.



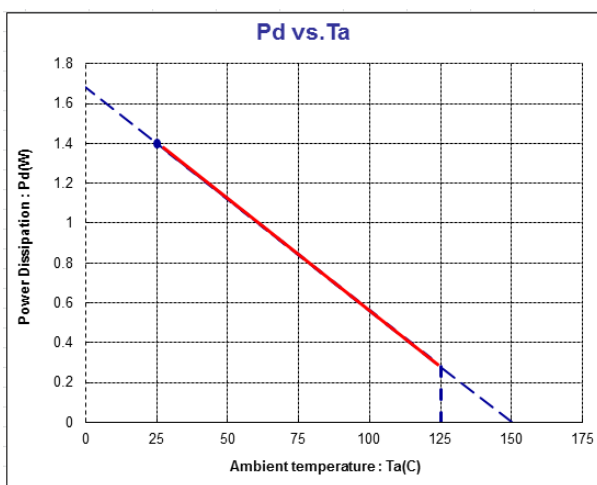
● Thermal Information

|               |  |          |
|---------------|--|----------|
| $\theta_{ja}$ | junction-to-ambient thermal resistance     | 89.2°C/W |
| $\Psi_{jt}$   | junction-to-top characterization parameter | 10.6°C/W |

Condition :

- FR4 PCB 25 x 25 mm<sup>2</sup>
- 1S1P-2 layers
- with 1 oz copper

● Power Dissipation



● How to predict Tj in the environment of the actual PCB

Step 1: Used the simulated  $\Psi_{jt}$  value listed above.

Step 2: Measure Tt value by using ~40 gauge thermocouple or thermo gun.

Tt : Temp. at top center of the package

Step 3: calculating power dissipation

$$P \cong (VCC - |V_{O\_Hi} - V_{O\_Li}|) \times I_{OUT} + VCC \times I_{cc}$$

Step 4: Estimate Tj value

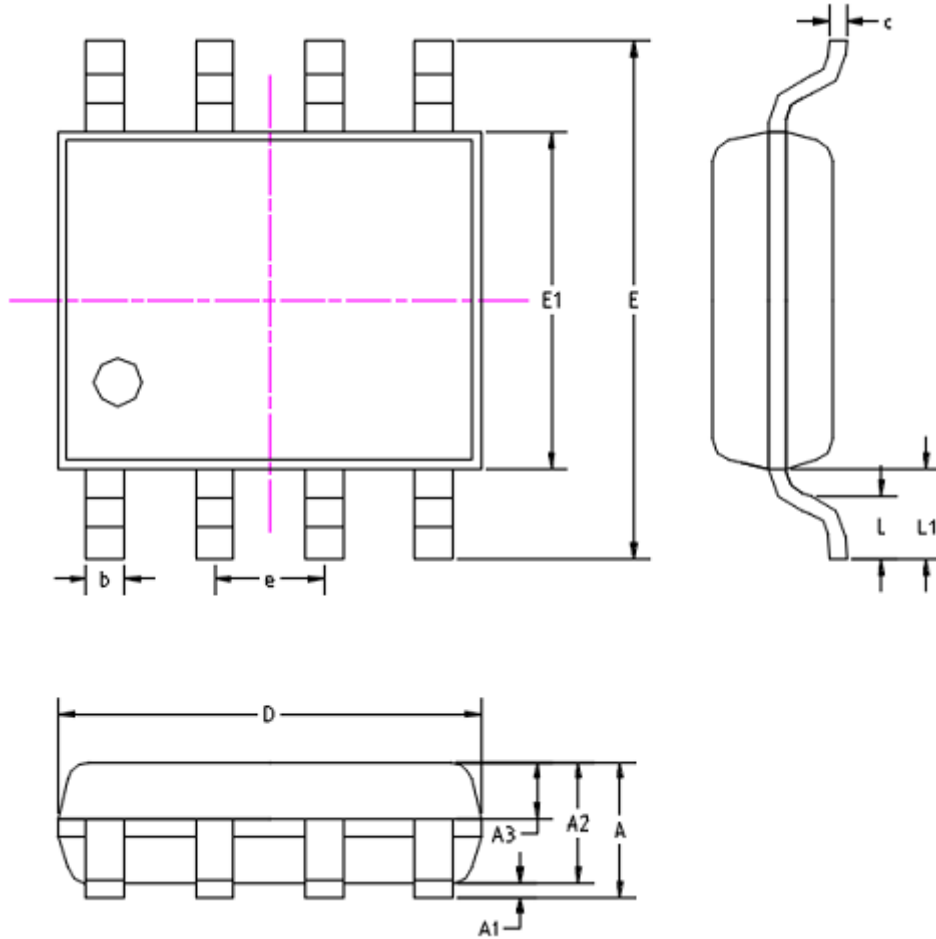
$$T_j = T_t + \Psi_{jt} \times P$$

Step 5: Calculated  $\theta_{ja}$  value of actual PCB

$$\theta_{ja} = \frac{(T_j - T_a)}{P} = \frac{T_t + \Psi_{jt} \times P - T_a}{P} = \frac{T_t - T_a}{P} + \Psi_{jt}$$

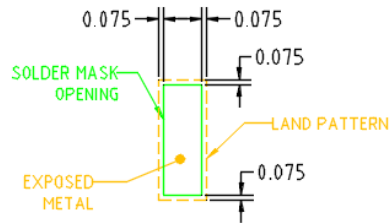
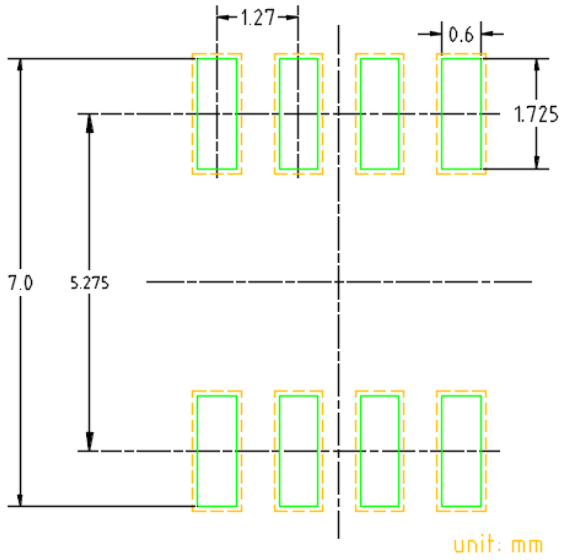
● Packaging outline --- SOP8

Unit: mm



| SYMBOL | MILLIMETERS |      | INCHES     |       |
|--------|-------------|------|------------|-------|
|        | Min.        | Max. | Min.       | Max.  |
| A      | --          | 1.75 | --         | 0.069 |
| A1     | 0.10        | 0.25 | 0.004      | 0.010 |
| A2     | 1.25        | 1.65 | 0.049      | 0.065 |
| A3     | 0.50        | 0.70 | 0.020      | 0.028 |
| b      | 0.39        | 0.49 | 0.015      | 0.190 |
| c      | 0.10        | 0.25 | 0.004      | 0.010 |
| D      | 4.70        | 5.10 | 0.185      | 0.201 |
| E      | 5.90        | 6.10 | 0.232      | 0.240 |
| E1     | 3.80        | 4.00 | 0.150      | 0.157 |
| e      | 1.27 TYP.   |      | 0.05 TYP.  |       |
| L      | 0.45        | 1.00 | 0.018      | 0.039 |
| L1     | 1.10 TYP    |      | 0.043 TYP. |       |

● Land Pattern And Solder Mask



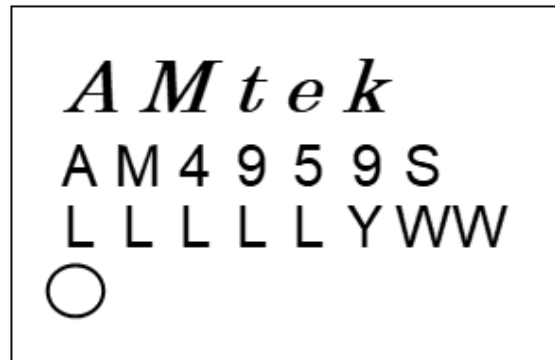
Solder Mask Define

SOP-8L LAND PATTERN

● **Marking Identification**

Package Type: SOP-8

Device : AM4959S

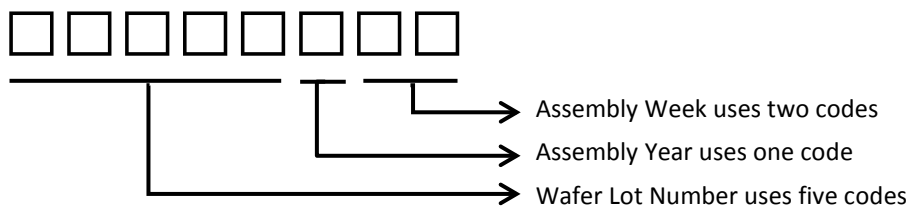


NOTE:

Row1: Logo

Row2: Device Name

Row3: Wafer Lot Number + Assembly Year + Assembly Week



Example: Wafer lot number is G8668 + Year 2021 is B + Week 31 is 31, we type "G8668B31" .

The last code of assembly year, explanation as below:

(Year: A=0, B=1, C=2, D=3, E=4, F=5, G=6, H=7, I=8, J=9. For example: year 2020=A)



● **Revision History**

| Date        | Revision | Changes  |
|-------------|----------|--|
| 5.Jan.2022  | V0.3     | New release  |
| 20.Jul.2022 | V0.4     | P12. POD update<br>P13. Add Land pattern and solder mask   |
| 14.Sep.2022 | V0.5     | P2. Operate Temperature Range up to 125°C<br>Add Storage Temperature Range condition.<br>P11. Update power dissipation curve |
| 27.Dec.2023 | V1.0     | P12. Packaging outline update  |

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